

SGM4568 8-Bit Bidirectional Voltage-Level Translator with Auto Direction Sensing

GENERAL DESCRIPTION

This 8-bit non-inverting voltage-level translator uses two separate configurable power-supply rails. The A ports are designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2V to 5.5V. The B ports are designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V voltage nodes. V_{CCA} should not exceed V_{CCB} .

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SGM4568 is designed so that the OE input circuit is supplied by V_{CCA} .

This device is fully specified for partial-power-down applications using I_{OFF} . The I_{OFF} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SGM4568 is available in Green TSSOP-20 and TQFN-3×3-20L packages. It operated over an ambient temperature range of -40°C to +85°C.

FEATURES

- 1.2V to 5.5V on A Ports and 1.65V to 5.5V on B Ports (V_{CCA} ≤ V_{CCB})
- V_{CC} Isolation: If Either V_{CC} is at GND,
 All Outputs are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption
- Push-Pull Output
- I_{OFF}: Supports Partial-Power-Down Mode Operation
- -40°C to +85°C Operating Temperature Range
- Available in Green TSSOP-20 and TQFN-3×3-20L Packages

APPLICATIONS

Smart-Phone
Portable Equipments
UART
GPIO



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
	TSSOP-20	-40°C to +85°C	SGM4568YTS20G/TR	SGM4568YTS20 XXXXX	Tape and Reel, 4000
SGM4568	TQFN-3×3-20L	-40°C to +85°C	SGM4568YTQG20G/TR	SGM 4568QG XXXXX	Tape and Reel, 4000

NOTE: XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

ADSOLUTE MAXIMUM NATINGS
V _{CCA} , Supply Voltage Range0.3V to 6V
$V_{\text{CCB}},$ Supply Voltage Range
V _I , Input Voltage Range
A Ports0.3V to 6V
B Ports0.3V to 6V
Vo, Voltage Range Applied to Any Output in the High-
Impedance or Power-Off State
A Ports0.3V to 6V
B Ports0.3V to 6V
Vo, Voltage Range Applied to Any Output in the High or Low
State (1)
A Ports0.3V to V _{CCA} + 0.3V
B Ports0.3V to V _{CCB} + 0.3V
I _{IK} , Input Clamp Current (V _I < 0)50mA
I _{OK} , Output Clamp Current (V _O < 0)25mA
Continuous Current through V _{CCA} , V _{CCB} , or GND±100mA
Continuous Current through V _{CCA} , V _{CCB} , or GND±100mA Junction Temperature150°C
Junction Temperature150°C
Junction Temperature
Junction Temperature
Junction Temperature

NOTE: 1. The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range	
V _{CCA}	1.2V to 5.5V
V _{CCB}	1.65V to 5.5V
High-Level Input Voltage, VIH	
Data Inputs	$V_{CCI} \times 0.85^{(4)}$ to V_{CCI}
OE Input	$V_{CCA} \times 0.85 \text{ to } 5.5V$
Low-Level Input Voltage, V _{IL}	
Data Inputs	0V to $V_{CCI} \times 0.2^{(4)}$
OE Input	0V to V _{CCA} × 0.2
Voltage Range Applied to Any Output	in the High-Impedance
or Power-Off State, Vo	
A Ports	0V to 5.5V
B Ports	0V to 5.5V
Input Transition Rise or Fall Rate, $\Delta t/\Delta l$	V
A Port Inputs	40ns/V (MAX)
B Port Inputs	40ns/V (MAX)
Operating Temperature Range	40°C to +85°C

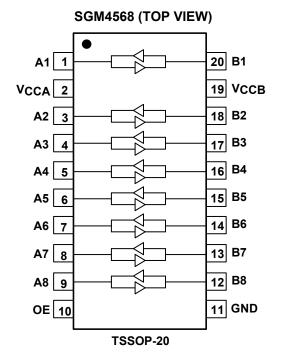
NOTES:

- 2. The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.
- 3. V_{CCA} must be less than or equal to V_{CCB} and must not exceed 5.5V.
- 4. V_{CCI} is the supply voltage associated with the input ports.

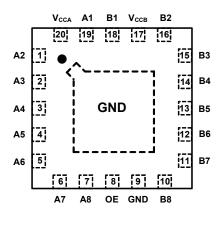
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PIN CONFIGURATIONS



SGM4568 (TOP VIEW)



TQFN-3×3-20L

PIN DESCRIPTION

F	PIN	NAME	FUNCTION			
TSSOP-20	TQFN-3×3-20L	NAME	FUNCTION			
1	19	A1	Input/Output 1. Referenced to V _{CCA} .			
2	20	V _{CCA}	A Ports Supply Voltage. $1.2V \le V_{CCA} \le 5.5V$ and $V_{CCA} \le V_{CCB}$.			
3	1	A2	Input/Output 2. Referenced to V _{CCA} .			
4	2	A3	Input/Output 3. Referenced to V _{CCA} .			
5	3	A4	Input/Output 4. Referenced to V _{CCA} .			
6	4	A5	Input/Output 5. Referenced to V _{CCA} .			
7	5	A6	Input/Output 6. Referenced to V _{CCA} .			
8	6	A7	Input/Output 7. Referenced to V _{CCA} .			
9	7	A8	Input/Output 8. Referenced to V _{CCA} .			
10	8	OE	Output Enable. Pull OE low to place all outputs in 3-state mode Referenced to V _{CCA} .			
11	9	GND	Ground.			
12	10	B8	Input/Output 8. Referenced to V _{CCB} .			
13	11	В7	Input/Output 7. Referenced to V _{CCB} .			
14	12	В6	Input/Output 6. Referenced to V _{CCB} .			
15	13	B5	Input/Output 5. Referenced to V _{CCB} .			
16	14	B4	Input/Output 4. Referenced to V _{CCB} .			
17	15	В3	Input/Output 3. Referenced to V _{CCB} .			
18	16	B2	Input/Output 2. Referenced to V _{CCB} .			
19	17	V _{CCB}	B Ports Supply Voltage. 1.65V ≤ V _{CCB} ≤ 5.5V.			
20	18	B1	Input/Output 1. Referenced to V _{CCB} .			
_	Exposed Pad	GND	Exposed pad should be soldered to PCB board and connected to GND or left floating.			

ELECTRICAL CHARACTERISTICS (1)

(Full = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.)

PARAMETER		CON	IDITIONS	TEMP	MIN	TYP	MAX	UNITS
A Ports High Level Output Voltage (V _{OHA})		1 - 2011	V _{CCA} = 1.2V	+25°C		1.05		
A Ports High Level Output	Voltage (Voha)	Ι _{ΟΗ} = -20μΑ	V _{CCA} = 1.4V to 5.5V	Full	V _{CCA} - 0.3			
A Ports Low Level Output Voltage (V _{OLA})		I _{OL} = 20μΑ	V _{CCA} = 1.2V	+25°C		0.1		V
A Ports Low Level Output	Voltage (V _{OLA})	Ι _{ΟL} – 20μΑ	V _{CCA} = 1.4V to 5.5V	Full			0.3	\ \ \
B Ports High Level Output	Voltage (V _{OHB})	I _{OH} = -20μA	V _{CCB} = 1.65V to 5.5V	Full	V _{CCB} - 0.3			-
B Ports Low Level Output	Voltage (V _{OLB})	I _{OL} = 20μA	V _{CCB} = 1.65V to 5.5V	Full			0.3	
Input Leakage Current	OE	OE = V _{CCA} or GND,		+25°C			±1	
(I ₁)	OL	$V_{CCA} = 1.2V \text{ to } 5.5V$	$V_{CCB} = 1.65V \text{ to } 5.5V$	Full			±1.5	
	A Ports	V_1 or $V_0 = 0V$ to 5.5		+25°C			±0.5	
Power Off Leakage	ATORS	$V_{CCA} = 0V, V_{CCB} = 0$	OV to 5.5V	Full			±1	μΑ
Current (I _{OFF})	B Ports	V_1 or $V_0 = 0V$ to 5.5		+25°C			±0.5	μΑ
	D FOILS	$V_{CCA} = 0V \text{ to } 5.5V,$	V _{CCB} = 0V	Full			±1	
3-State Output Leakage	A or B Ports	OE = GND, V _{CCA} =	OE = GND, V _{CCA} = 1.2V to 5.5V,				±0.5	
(I _{OZ})	AUIDFUIS	V _{CCB} = 1.65V to 5.5V		Full			±1	
			$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		
Ouissaant Sunnly Current	(1)	$V_{I} = V_{CCI} \text{ or GND},$ $I_{O} = 0,$ $OE = V_{CCA}$	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$				12	
Quiescent Supply Current	(ICCA)		$V_{CCA} = 5.5V,$ $V_{CCB} = 0V$	Full			12	μΑ
			$V_{CCA} = 0V,$ $V_{CCB} = 5.5V$				-1	
			V _{CCA} = 1.2V, V _{CCB} = 1.65V to 5.5V	+25°C		1		
Quiescent Supply Current	(1)	$V_i = V_{CCi}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$				10	^
Quiescent Supply Current	(ICCB)	$OE = V_{CCA}$	$V_{CCA} = 5.5V,$ $V_{CCB} = 0V$	Full			-1	μΑ
			$V_{CCA} = 0V,$ $V_{CCB} = 5.5V$				9	
Quiescent Supply Current	(1 +1)	$V_i = V_{CCi}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		1		^
Quiescent Supply Current	(ICCA I ICCB)	OE = V _{CCA}	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			19	μΑ
Quioscont Supply Current	(1)	$V_i = V_{CCI}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		μA
Quiescent Supply Current (I _{CCZA})		OE = GND	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			12	μΑ
Quiescent Supply Current (I _{CCZB})		$V_i = V_{CCi}$ or GND, $I_0 = 0$,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		μA
Quiescent Supply Cullent	(ICCZB)	0E = GND	$V_{CCA} = 1.4V \text{ to } 5.5V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			9	μΛ
OE Input Capacitance (C)	V _{CCA} = 1.2V to 5.5V	/, V _{CCB} = 1.65V to 5.5V	+25°C		5.2		pF
Input/Output	A Ports	\/ = 1.2\/ +0.E.E\	/ \/ = 1.65\/ +0.5.5\/	+25°C		4.4		pE
Capacitance (C _{IO})	B Ports	V _{CCA} - 1.2V (U 3.5)	$V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		4.4		pF

NOTE:

1. V_{CCI} is the supply voltage associated with the input ports.

TIMING REQUIREMENTS

		V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LIMITE
		TYP	TYP	TYP	TYP	UNITS
(T _A = +25°C, V _{CCA} = 1.2	V, unless otherv	vise noted.)				
Data Rate		20	20	20	20	Mbps
Pulse Duration (t _w)	Data Inputs	50	50	50	50	ns
(T _A = +25°C, V _{CCA} = 1.5	V, unless otherv	vise noted.)				
Data Rate		50	50	50	50	Mbps
Pulse Duration (t _w)	Data Inputs	20	20	20	20	ns
(T _A = +25°C, V _{CCA} = 1.8	3V, unless otherv	vise noted.)				
Data Rate		52	60	60	60	Mbps
Pulse Duration (t _w)	Data Inputs	19	17	17	17	ns
$(T_A = +25^{\circ}C, V_{CCA} = 2.5)$	V, unless otherv	vise noted.)				
Data Rate			70	100	100	Mbps
Pulse Duration (t _w)	Data Inputs		14	10	10	ns
$(T_A = +25^{\circ}C, V_{CCA} = 3.3)$	V, unless otherv	vise noted.)				
Data Rate				100	100	Mbps
Pulse Duration (t _w)	Data Inputs			10	10	ns
(T _A = +25°C, V _{CCA} = 5V	, unless otherwi	se noted.)				
Data Rate					100	Mbps
Pulse Duration (t _w)	Data Inputs				10	ns

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.2V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS					
PAR	AWEIEK	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS					
	t _{PLH}	Α	В	22.9	19.8	19.0	18.9						
	t _{PHL}	<u> </u>	В	30.5	29.0	30.0	31.3	200					
t _{PD}	t _{PLH}	В	^	32.0	33.2	30.1	28.9	ns					
	t _{PHL}	В	Α	22.1	19.5	18.1	14.7						
	t _{PZH}		А	74.1	71.5	69.0	62.9						
	t _{PZL}	OE	А	60.0	54.2	52.6	50.0						
t _{EN}	t _{PZH}	OE .	D	45.3	41.4	40.8	42.2	ns					
	t _{PZL}		В	69.5	66.8	67.3	68.0						
	t _{PHZ}		^	1060	1070	1040	1030						
	t _{PLZ}	OE	Α	500	500	510	520						
t _{DIS}	t _{PHZ}		OE	OE	OE	OE .	UE		В	1090	1120	1100	1130
	t _{PLZ}		В	570	590	580	570						
	t _{rA}	A Ports F	Rise Time	21.5	22.2	21.2	20.2	ns					
	t _{fA}	A Ports	Fall Time	9.6	10.1	9.5	8.7	ns					
	t _{rB}	B Ports F	Rise Time	3.9	2.3	2.0	1.7	ns					
	t _{fB}	B Ports	Fall Time	2.3	1.9	1.7	1.5	ns					
1	SK(O)	Channel-to-C	Channel Skew	1	1	1	1	ns					
	ta Rate			20	20	20	20	Mbps					

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.5V, unless otherwise noted.)$

DAD	AMETER	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LINUTO
PAR	AIVIETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS
	t _{PLH}	Α	В	13.9	12.1	10.9	10.2	
	t _{PHL}	1 ^	Ь	13.7	12.2	11.3	11.3	200
t _{PD}	t _{PLH}	В	А	12.3	13.7	13.2	9.4	ns
	t _{PHL}		A	11.1	11.5	9.0	7.5	
	t _{PZH}		۸	32.0	31.3	31.2	30.3	
	t _{PZL}	OE	Α	32.9	28.8	27.3	26.0	200
t_{EN}	t _{PZH}	OE .	В	29.2	23.4	21.7	21.2	ns
	t _{PZL}		Ь	33.5	29.6	28.9	29.9	
	t _{PHZ}		Α	1030	1030	1050	1050	
	t _{PLZ}	OE	A	510	520	520	510	
t _{DIS}	t _{PHZ}		OE	OE.	OE OE	B 1070 1120	1080	1110
	t _{PLZ}		В	530	570	570	560	
	t _{rA}	A Ports F	Rise Time	8.0	6.0	5.8	4.8	ns
	t _{fA}	A Ports I	-all Time	3.9	2.9	2.8	1.6	ns
t_{rB}		B Ports F	Rise Time	4.0	2.3	2.0	1.8	ns
	t _{fB}	B Ports I	all Time	2.4	1.9	1.8	1.6	ns
1	t _{SK(O)}	Channel-to-C	hannel Skew	0.5	0.5	0.5	0.5	ns
Da	ta Rate			50	50	50	50	Mbps

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 1.8V, unless otherwise noted.)$

DAR	AMETED	FROM	то	V _{CCB} = 1.8V	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS
PARA	AIVIETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP TYP 9.0 8.3 8.2 7.7 8.0 7.4 7.4 5.7 23.2 20.8 20.6 20.0 17.2 16.4 20.8 21.8 1090 1070 530 540 1090 1100		UNITS
	t _{PLH}	A	В	13.8	10.2	9.0	8.3	
	t _{PHL}	A	В	10.6	9.0	8.2	7.7	no
LPD.	t _{PLH}	В	А	11.2	9.9	8.0	7.4	ns
	t _{PD}	ь	A	8.6	6.8	7.4	5.7	
	t _{PZH}		۸	21.6	21.9	23.2	20.8	
	t _{PZL}	OF	Α	26.0	21.4	20.6	20.0	
LEN	t _{PZH}	OE —	В	24.8	19.0	17.2	16.4	ns
	t _{PZL}		Ь	24.7	21.3	20.8	21.8	
	t _{PHZ}		A	1080	1080	1090	1070	
	t _{PLZ}	OE		540	540	530	540	no
LDIS	t _{PHZ}	OE	В	1070	1110	1090	1100	ns
	t _{PLZ}		Б	530	560	560	560	
	t _{rA}	A Ports F	Rise Time	4.7	4.2	3.5	3.0	ns
	t _{fA}	A Ports I	all Time	2.6	2.1	2.6	4.1	ns
	t _{rB}	B Ports F	Rise Time	3.4	2.3	1.9	1.7	ns
	t _{fB}	B Ports I	all Time	2.4	1.7	1.5	1.5	ns
t	SK(O)	Channel-to-C	hannel Skew	0.5	0.5	0.5	0.5	ns
	ta Rate			52	60	60	60	Mbps

SWITCHING CHARACTERISTICS

(T_A = +25°C, V_{CCA} = 2.5V, unless otherwise noted.)

DAD	AMETER	FROM	то	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LINUTO
PAR	AMETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	UNITS
	t _{PLH}	А	В	8.2	7.7	6.1	
	t _{PHL}		Ь	6.6	4.5	5.1	200
t _{PD}	t _{PLH}	В	А	6.4	6.2	4.9	ns
	t _{PHL}	Ь	A	5.8	3.9	3.9	
	t _{PZH}		А	15.0	15.4	18.4	
	t _{PZL}	OF	A	16.5	14.2	13.9	ns
t _{EN}	t _{PZH}	OE ·	В	15.6	15.6	12.8	115
	t _{PZL}		Б	15.5	16.3	15.2	
	t _{PHZ}		А	1090	1100	1110	
	t _{PLZ}	0.5	A	570	570	570	
t _{DIS}	t _{PHZ}	OE	В	1100	1080	1090	ns
	t _{PLZ}		В	570	560	550	
	t _{rA}	A Ports	Rise Time	2.4	3.3	3.3	ns
	t _{fA}	A Ports	Fall Time	2.0	3.2	2.5	ns
	t _{rB}	B Ports	Rise Time	2.3	2.6	2.5	ns
	t _{fB}	B Ports	Fall Time	1.9	3.1	1.3	ns
	t _{SK(O)}	Channel-to-0	Channel Skew	0.5	0.5	0.5	ns
Da	ta Rate			70	100	100	Mbps

SWITCHING CHARACTERISTICS

 $(T_A = +25^{\circ}C, V_{CCA} = 3.3V, unless otherwise noted.)$

DAD	AMETED	FROM	то	V _{CCB} = 3.3V	V _{CCB} = 5V	LIMITO	
PAR	AMETER	(INPUT)	(OUTPUT)			UNITS	
	t _{PLH}	A	В	5.6	3.7		
	t _{PHL}		В	4.9	3.7		
t _{PD}	t _{PLH}	В	Α	4.3	3.6	ns	
	t _{PHL}]	A	4.2	2.6		
	t _{PZH}		۸	13.3	15.0		
	t _{PZL}	05	Α	14.4	13.1		
t _{EN}	t _{PZH}	OE	OE	6	14.5	13.3	ns
	t _{PZL}]	В	13.5	15.5		
	t _{PHZ}		А	1080	1090		
	t _{PLZ}	05	A	570	570		
t _{DIS}	t _{PHZ}	- OE		1060	1100	ns	
	t _{PLZ}]	В	560	560		
	t _{rA}	A Ports	Rise Time	2.0	2.0	ns	
	t _{fA}	A Ports	Fall Time	1.7	1.6	ns	
	t _{rB}	B Ports	Rise Time	2.1	1.7	ns	
	t_{fB}	B Ports Fall Time		2.1	1.5	ns	
1	SK(O)	Channel-to-0	Channel Skew	0.5	0.5	ns	
	ta Rate			100	100	Mbps	

SWITCHING CHARACTERISTICS

($T_A = +25$ °C, $V_{CCA} = 5V$, unless otherwise noted.)

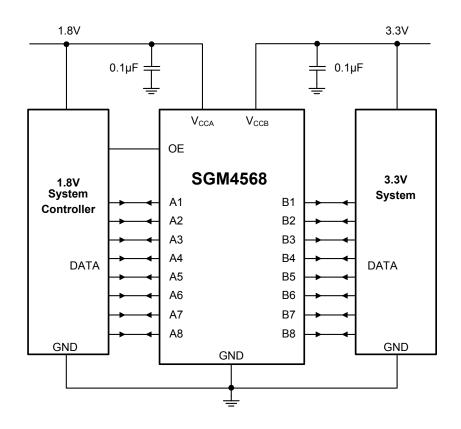
DAD	AMETED	FROM	то	V _{CCB} = 5V	LINUTO					
PARA	AMETER	(INPUT)	(OUTPUT)	TYP	UNITS					
	t _{PLH}	А	В	3.7						
	t _{PHL}		В	3.2						
t _{PD}	t _{PLH}	в А	۸	2.9	ns					
	t _{PHL}	Ь	A	2.7						
	t _{PZH}		Δ.	15.6						
	N t _{PZL}	OE	Α	14.3						
t_{EN}		OE OE	D	15.3	ns					
	t _{PZL}		В	15.3						
	t _{PHZ}		Α	1090						
	t _{PLZ}	05	OF	05	OF	05	OF	Α	560	
t _{DIS}	t _{PHZ}	OE	В	1090	ns					
	t _{PLZ}		В	560						
	t _{rA}	A Ports F	Rise Time	1.5	ns					
	t _{fA}	A Ports I	Fall Time	1.4	ns					
	t _{rB}	B Ports F	Rise Time	2.2	ns					
	t _{fB}	B Ports I	Fall Time	1.3	ns					
t	SK(O)	Channel-to-C	Channel Skew	0.5	ns					
	a Rate			100	Mbps					

OPERATING CHARACTERISTICS

 $(T_A = 25^{\circ}C, unless otherwise noted.)$

			V _{CCA}									
		TEST CONDITIONS	1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V	3.3V	5V	
F	PARAMETER		V _{CCB}								UNIT	
			5V	1.8V	1.8V	1.8V	2.5V	5V	3.3V	5V	5V	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	
	A Port Inputs, B Port Outputs	$C_L = 0,$ f = 10MHz, $t_r = t_f = 1ns,$ $OE = V_{CCA}$ (Outputs Enabled)	68	64	34	9	9	10	11	11	12	- pF
C _{PDA}	B Port Inputs, A Port Outputs		6	6	6	6	6	6	6	6	6	
C _{PDB}	A Port Inputs, B Port Outputs		7	6	6	6	6	6	6	6	6	
	B Port Inputs, A Port Outputs		40	97	10	9	9	10	10	11	12	
C _{PDA} -	A Port Inputs, B Port Outputs	$C_L = 0$, f = 10MHz, $t_r = t_f = 1ns$, OE = GND (Outputs Disabled)	0.003	0.002	0.004	0.003	0.004	0.003	0.003	0.003	0.003	
	B Port Inputs, A Port Outputs		0.004	0.003	0.007	0.004	0.004	0.003	0.002	0.002	0.003	pF
	A Port Inputs, B Port Outputs		0.004	0.008	0.009	0.007	0.004	0.003	0.003	0.003	0.003	ρι
	B Port Inputs, A Port Outputs		0.004	0.008	0.009	0.008	0.003	0.003	0.003	0.003	0.002	

TYPICAL APPLICATION CIRCUIT



APPLICATION INFORMATION

Applications

The SGM4568 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

Architecture

The SGM4568 architecture (see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a DC state, the output drivers of the SGM4568 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one-shots detect rising or falling edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one-shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70Ω at $V_{\rm CCO}$ = 1.2V to 1.8V, 50Ω at $V_{\rm CCO}$ = 1.8V to 3.3V, and 40Ω at $V_{\rm CCO}$ = 3.3V to 5V.

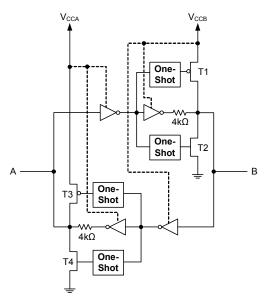
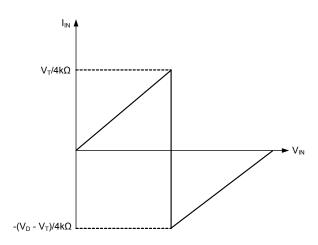


Figure 1. Architecture of SGM4568 I/O Cell

Input Driver Requirements

Typical I_{IN} vs. V_{IN} characteristics of the SGM4568 are shown in Figure 2. For proper operation, the device driving the data I/Os of the SGM4568 must have drive strength of at least $\pm 2\text{mA}$.



A. V_T is the input threshold voltage of the SGM4564 (typically $V_{CCI}/2$). B. V_D is the supply voltage of the external driver.

Figure 2. Typical I_{IN} vs. V_{IN} Curve

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The SGM4568 has circuitry that disables all output ports when either V_{CC} is switched off $(V_{CCA/B} = 0V)$.

Enable and Disable

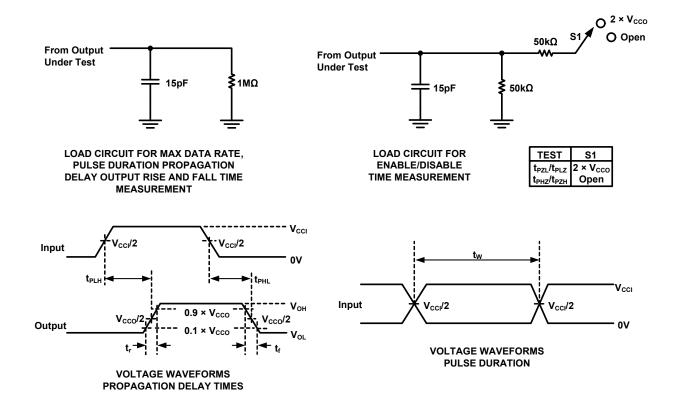
The SGM4568 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{DIS}) indicates the delay between when OE goes low and when the outputs are actually disabled (Hi-Z). The enable time (t_{EN}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pull-Up or Pull-Down Resistors on I/O Lines

The SGM4568 is designed to drive capacitive loads of up to 70pF. The output drivers of the SGM4568 have low DC drive strength. If pull-up or pull-down resistors are connected externally to the data I/Os, their values must be kept higher than $50 k\Omega$ to ensure that they do not contend with the output drivers of the SGM4568.

For the same reason, the SGM4568 should not be used in applications such as I^2C or 1-wire where an open-drain driver is connected on the bidirectional data I/C

PARAMETER MEASUREMENT INFORMATION



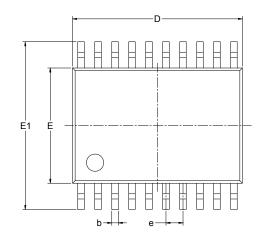
NOTES:

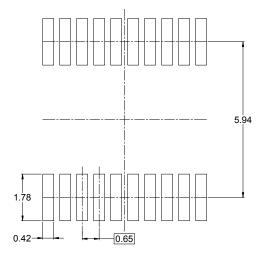
- 1. C_L includes probe and jig capacitance.
- 2. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, $Z_0 = 50\Omega$, $dv/dt \geq 1V/ns$.
- 3. The outputs are measured one at a time, with one transition per measurement.
- 4. t_{PLH} and t_{PHL} are the same as t_{PD} .
- 5. V_{CCI} is the V_{CC} associated with the input ports.
- 6. V_{CCO} is the V_{CC} associated with the output ports.
- 7. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuits and Voltage Waveforms

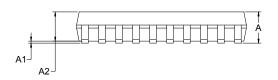
PACKAGE OUTLINE DIMENSIONS

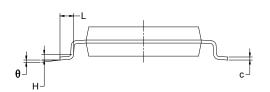
TSSOP-20





RECOMMENDED LAND PATTERN (Unit: mm)

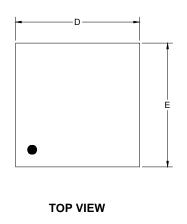


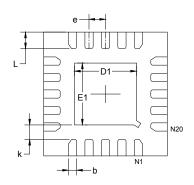


Symbol	_	nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
Α		1.100		0.043		
A1	0.050	0.150	0.002	0.006		
A2	0.800	1.000	0.031	0.039		
b	0.190	0.300	0.007	0.012		
С	0.090	0.200	0.004	0.008		
D	6.400	6.600	0.252	0.259		
Е	4.300	4.500	0.169	0.177		
E1	6.250	6.550	0.246	0.258		
е	0.650	BSC	0.026 BSC			
L	0.500	0.700	0.02	0.028		
Н	0.25	TYP	0.01	TYP		
θ	1°	7°	1°	7°		

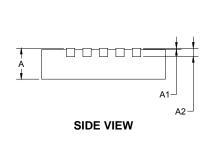
PACKAGE OUTLINE DIMENSIONS

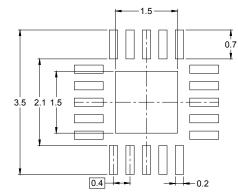
TQFN-3×3-20L





BOTTOM VIEW



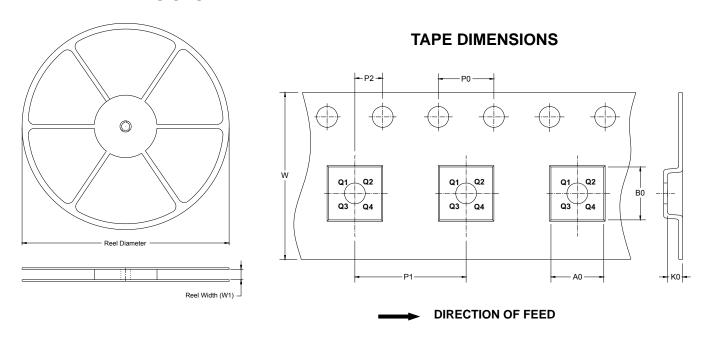


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	-	nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
Α	0.700	0.800	0.028	0.031		
A1	0.000	0.050	0.000	0.002		
A2	0.203	REF	0.008 REF			
D	2.924	3.076	0.115	0.121		
D1	1.400	1.600	0.055	0.063		
E	2.924	3.076	0.115	0.121		
E1	1.400	1.600 0.055		0.063		
k	0.200 MIN		0.008	3 MIN		
b	0.150	0.250	0.006	0.010		
е	0.400 TYP		0.016	TYP		
L	0.324	0.476	0.013	0.019		

TAPE AND REEL INFORMATION

REEL DIMENSIONS

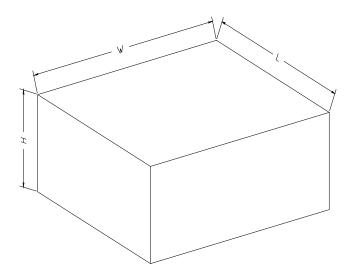


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TSSOP-20	13"	12.4	6.8	6.85	1.7	4.0	8.0	2.0	12.0	Q1
TQFN-3×3-20L	13"	12.4	3.3	3.3	1.1	4.0	4.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13"	386	280	370	5	DD0002